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09/843/28

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Terms	Documents
L5 and (resist near5 patterning)	3

Database:

US Patents Full-Text Database	▲
US Pre-Grant Publication Full-Text Database	
JPO Abstracts Database	
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Derwent World Patents Index	
IBM Technical Disclosure Bulletins	▼

Search:

L6

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 result set
DB=USPT; PLUR=YES; OP=OR

<u>L6</u>	L5 and (resist near5 patterning)	3	<u>L6</u>
<u>L5</u>	L4 and (copper near2 plating)	65	<u>L5</u>
<u>L4</u>	L1 and cmp	202	<u>L4</u>
<u>L3</u>	L1 and (cmp or (chemical mechanical polishing))	459	<u>L3</u>
<u>L2</u>	L1 and cmp or (chemical mechanical polishing)	1079242	<u>L2</u>
<u>L1</u>	copper adj seed	500	<u>L1</u>

END OF SEARCH HISTORY

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L6: Entry 1 of 3

File: USPT

Feb 26, 2002

US-PAT-NO: 6350688

DOCUMENT-IDENTIFIER: US 6350688 B1

TITLE: Via RC improvement for copper damascene and beyond technology

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KWIC
Draw Desc	Image										

☐ 2. Document ID: US 6225226 B1

L6: Entry 2 of 3

File: USPT

May 1, 2001

US-PAT-NO: 6225226

DOCUMENT-IDENTIFIER: US 6225226 B1

TITLE: Method for processing and integrating copper interconnects

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KWIC
Draw Desc	Image										

☐ 3. Document ID: US 6184138 B1

L6: Entry 3 of 3

File: USPT

Feb 6, 2001

US-PAT-NO: 6184138

DOCUMENT-IDENTIFIER: US 6184138 B1

TITLE: Method to create a controllable and reproducible dual copper damascene structure

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	KWIC
Draw Desc	Image									

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Terms	Documents
L5 and (resist near5 patterning)	3

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Terms	Documents
L10 and (diffusion near barrier)	3

Database:

US Patents Full-Text Database	▲
US Pre-Grant Publication Full-Text Database	
JPO Abstracts Database	
EPO Abstracts Database	
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Search:

L11

[Refine Search](#)[Recall Text](#)[Clear](#)**Search History****DATE:** Sunday, September 15, 2002 [Printable Copy](#) [Create Case](#)

Set Name Query

side by side

Hit Count Set Name

result set

DB=USPT; PLUR=YES; OP=OR

<u>L11</u>	L10 and (diffusion near barrier)	3	<u>L11</u>
<u>L10</u>	L9 and patterning	7	<u>L10</u>
<u>L9</u>	L8 and plating	9	<u>L9</u>
<u>L8</u>	L4 and (developing near5 (resist or photoresist))	13	<u>L8</u>
<u>L7</u>	L4 and (trimming near5 resist)	0	<u>L7</u>
<u>L6</u>	L5 and (resist near5 patterning)	3	<u>L6</u>
<u>L5</u>	L4 and (copper near2 plating)	65	<u>L5</u>
<u>L4</u>	L1 and cmp	202	<u>L4</u>
<u>L3</u>	L1 and (cmp or (chemical mechanical polishing))	459	<u>L3</u>
<u>L2</u>	L1 and cmp or (chemical mechanical polishing)	1079242	<u>L2</u>
<u>L1</u>	copper adj seed	500	<u>L1</u>

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L10: Entry 1 of 7

File: USPT

Aug 13, 2002

US-PAT-NO: 6433432

DOCUMENT-IDENTIFIER: US 6433432 B1

TITLE: Semiconductor device having fluorinated insulating film and reduced fluorine at interconnection interfaces and method of manufacturing the same

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

[KWC](#)☐ 2. Document ID: US 6420261 B2

L10: Entry 2 of 7

File: USPT

Jul 16, 2002

US-PAT-NO: 6420261

DOCUMENT-IDENTIFIER: US 6420261 B2

TITLE: Semiconductor device manufacturing method

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

[KWC](#)☐ 3. Document ID: US 6280640 B1

L10: Entry 3 of 7

File: USPT

Aug 28, 2001

US-PAT-NO: 6280640

DOCUMENT-IDENTIFIER: US 6280640 B1

TITLE: Process for manufacturing a chip carrier substrate

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

[KWC](#)☐ 4. Document ID: US 6262376 B1

L10: Entry 4 of 7

File: USPT

Jul 17, 2001

US-PAT-NO: 6262376
DOCUMENT-IDENTIFIER: US 6262376 B1

TITLE: Chip carrier substrate

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

KWIC

☐ 5. Document ID: US 6110819 A

L10: Entry 5 of 7 File: USPT Aug 29, 2000

US-PAT-NO: 6110819
DOCUMENT-IDENTIFIER: US 6110819 A

TITLE: Interconnect structure using Al.sub.2 Cu for an integrated circuit chip

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

KWIC

☐ 6. Document ID: US 5925933 A

L10: Entry 6 of 7 File: USPT Jul 20, 1999

US-PAT-NO: 5925933
DOCUMENT-IDENTIFIER: US 5925933 A

TITLE: Interconnect structure using Al.sub.2 -Cu for an integrated circuit chip

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

KWIC

☐ 7. Document ID: US 5565707 A

L10: Entry 7 of 7 File: USPT Oct 15, 1996

US-PAT-NO: 5565707
DOCUMENT-IDENTIFIER: US 5565707 A

TITLE: Interconnect structure using a Al.sub.2 Cu for an integrated circuit chip

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
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KWIC

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Terms	Documents
L9 and patterning	7

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L11: Entry 1 of 3

File: USPT

Aug 29, 2000

US-PAT-NO: 6110819

DOCUMENT-IDENTIFIER: US 6110819 A

TITLE: Interconnect structure using Al.sub.2 Cu for an integrated circuit chip

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	KWIC
Draw Desc	Image									

☐ 2. Document ID: US 5925933 A

L11: Entry 2 of 3

File: USPT

Jul 20, 1999

US-PAT-NO: 5925933

DOCUMENT-IDENTIFIER: US 5925933 A

TITLE: Interconnect structure using Al.sub.2 -Cu for an integrated circuit chip

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	KWIC
Draw Desc	Image									

☐ 3. Document ID: US 5565707 A

L11: Entry 3 of 3

File: USPT

Oct 15, 1996

US-PAT-NO: 5565707

DOCUMENT-IDENTIFIER: US 5565707 A

TITLE: Interconnect structure using a Al.sub.2 Cu for an integrated circuit chip

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	KWIC
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Terms	Documents
L10 and (diffusion near barrier)	3

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